CLAIMS

- A flexible structure comprising integrated sensing means, said integrated sensing means being electrically accessible and being at least partly encapsulated in a flexible and electrically insulating body, said integrated sensing means being adapted to sense deformations of the flexible structure.
 - 2. A flexible structure according to claim 1, wherein the flexible and electrically insulating body is a polymer-based body.

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- 3. A flexible structure according to claim 2, wherein the flexible polymer-based body is formed by a first and a second polymer layer.
- 4. A flexible structure according to claim 3, wherein the integrated sensing means is positioned between the first and the second polymer layer.
 - 5. A flexible structure according to claim 1, wherein the integrated sensing means forms a resistor.
- 20 6. A flexible structure according to claim 2, wherein the flexible polymer-based body is formed by an SU-8 polymer.
 - 7. A flexible structure according to claim 3 , wherein the polymer layers are SU-8 polymers.

- 8. A flexible structure according to claim 5, wherein the resistor is formed by a conducting layer.
- 9. A flexible structure according to claim 8, wherein the conducting layer is a metal layer.
 - 10. A flexible structure according to claim 9, wherein the metal layer is a gold layer.

- 11. A flexible structure according to claim 8, wherein the conducting layer comprises a semiconductor material.
- 12. A flexible structure according to claim 11, wherein the semiconductor material is silicon.
- 13. A flexible structure according to claim 1, further comprising a substantially rigid portion comprising an integrated electrical conductor being at least partly encapsulated in a substantially rigid and electrically insulating body, said integrated electrical conductor being connected to the integrated sensing means and being electrically accessible via a contact terminal on an exterior surface of the substantially rigid body.
- 14. A flexible structure according to claim 13, wherein the substantially rigid
 body is formed by a first and a second polymer layer, and wherein the integrated electrical conductor is positioned between the first and the second polymer layer.
- 15. A flexible structure according to claim 14, wherein the polymer layers20 forming the substantially rigid body are SU-8 polymer layers.
 - 16. A flexible structure according to claim 13, wherein the integrated electrical conductor is formed by a metal layer.
- 25 17. A flexible structure according to claim 16, wherein the metal layer is a gold layer.
 - 18. A flexible structure according to claim 13, wherein the integrated electrical conductor comprises a semiconductor material.
 - 19. A flexible structure according to claim 18, wherein the semiconductor material is silicon.

- 20. A chip comprising a flexible structure according to claim 5, said chip further comprising at least three resistors on a substrate.
- 21. A chip comprising two flexible structures according to claim 5, said chip 5 further comprising two resistors on a substrate.
 - 22. A chip according to claim 21, wherein the substrate is a SU-8 polymer substrate.
- 10 23. A chip according to claim 21, wherein the substrate is a silicon substrate.
 - 24. A chip according to claim 21, wherein each of the flexible structures comprises one resistor, and wherein the four resistors are connected to form a Wheatstone Bridge.

- 25. A sensor comprising a chip according to claim 24.
- 26. An actuator comprising a flexible structure comprising integrated actuator means, said integrated actuator means being electrically accessible and being
 at least partly encapsulated in a flexible and electrically insulating body, said integrated actuator means being adapted to induce deformations of the flexible structure.
- 27. An actuator according to claim 26, wherein the integrated actuator means
 25 comprises a metal layer and wherein the flexible and electrically insulating
 body is a polymer-based body.
 - 28. An actuator according to claim 27, wherein the polymer-based body is formed by an SU-8 polymer.

29. A chip processing method comprising

- providing a first insulating layer and patterning this first insulating layer so as to form an upper part of a cantilever,

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- providing a first conducting layer and patterning this first conducting layer so as to form at least one conductor on a first area of the patterned first insulator,
- providing a second conducting layer and patterning this second conducting layer so as to form at least one resistor on a second area of the patterned first insulator, and
- providing a second insulating layer so as to at least partly encapsulate the
 patterned first and second conducting layers, and patterning this second insulating layer so as to form a lower part of a cantilever.
 - 30. A chip processing method according to claim 29, wherein the insulating layers are polymer layers.

- 31. A chip processing method according to claim 30, wherein the insulating layers are SU-8 polymer layers.
- 32. A chip processing method according to claim 29, wherein the conducting layers are metal layers.
 - 33. A chip processing method according to claim 32, wherein the metal layers are gold layers.
- 30 34. A chip processing method according to claim 29, further comprising the step of providing a relatively thicker layer on the second insulating layer and patterning the relatively thicker layer so as to form a substrate.

- 35. A chip processing method according to claim 34, wherein the relatively thicker layer is a polymer layer.
- 36. A chip processing method according to claim 34, wherein the relatively thicker layer is a silicon layer.

- 37. A chip processing method according to claim 34, further comprising the steps of
- providing a sacrificial layer on a silicon wafer, wherein the first insulating layer is provided on the sacrificial layer, and
 - removing the silicon wafer after the providing and the patterning of the relatively thicker layer.
- 15 38. A chip processing method according to claim 35, wherein the relatively thick polymer layer is a SU-8 polymer layer.